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# FDMC86102L

## N-Channel Shielded Gate PowerTrench<sup>®</sup> MOSFET

100 V, 18 A, 23 mΩ

### Features

- Shielded Gate MOSFET Technology
- Max  $r_{DS(on)}$  = 23 mΩ at  $V_{GS} = 10$  V,  $I_D = 7$  A
- Max  $r_{DS(on)}$  = 34 mΩ at  $V_{GS} = 4.5$  V,  $I_D = 5.5$  A
- Low Profile - 1 mm max in Power 33
- RoHS Compliant

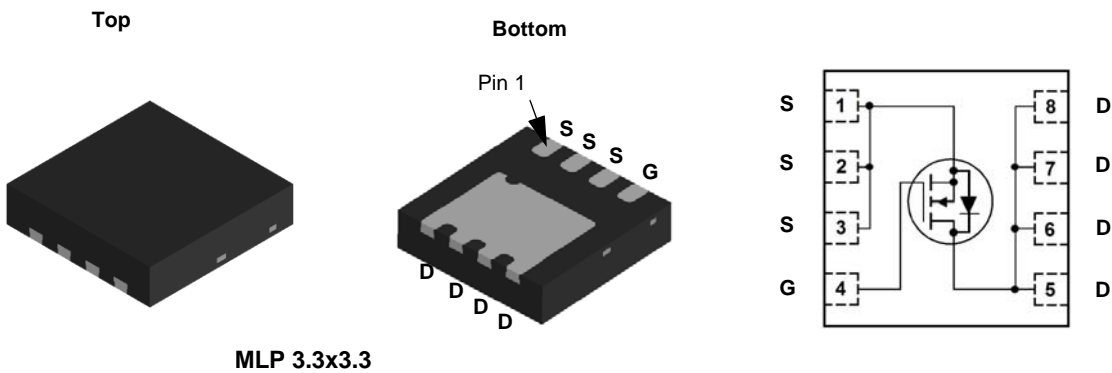


### General Description

This N-Channel MOSFET is produced using Fairchild Semiconductor's advanced PowerTrench<sup>®</sup> process that incorporates Shielded Gate technology. This process has been optimized for the on-state resistance and yet maintain superior switching performance.

### Application

- DC - DC Conversion



MLP 3.3x3.3

### MOSFET Maximum Ratings $T_A = 25$ °C unless otherwise noted

Symbol	Parameter	Rated Value	Units
$V_{DS}$	Drain to Source Voltage	100	V
$V_{GS}$	Gate to Source Voltage	±20	V
$I_D$	Drain Current -Continuous	$T_C = 25$ °C	A
	-Continuous	$T_A = 25$ °C (Note 1a)	
	-Pulsed		
$E_{AS}$	Single Pulse Avalanche Energy	(Note 3)	mJ
$P_D$	Power Dissipation	$T_C = 25$ °C	W
	Power Dissipation	$T_A = 25$ °C (Note 1a)	
$T_J, T_{STG}$	Operating and Storage Junction Temperature Range	-55 to +150	°C

### Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a) 53	

### Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC86102L	FDMC86102L	Power 33	13 "	12 mm	3000 units

FDMC86102L N-Channel Shielded Gate PowerTrench<sup>®</sup> MOSFET

## Electrical Characteristics $T_J = 25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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### Off Characteristics

$BV_{DSS}$	Drain to Source Breakdown Voltage	$I_D = 250\ \mu\text{A}, V_{GS} = 0\ \text{V}$	100			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250\ \mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		71		mV/ $^\circ\text{C}$
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 80\ \text{V}, V_{GS} = 0\ \text{V}$			1	$\mu\text{A}$
$I_{GSS}$	Gate to Source Leakage Current	$V_{GS} = \pm 20\ \text{V}, V_{DS} = 0\ \text{V}$			$\pm 100$	nA

### On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250\ \mu\text{A}$	1	1.8	3	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250\ \mu\text{A}$ , referenced to $25\text{ }^\circ\text{C}$		-6		mV/ $^\circ\text{C}$
$r_{DS(on)}$	Static Drain to Source On Resistance	$V_{GS} = 10\ \text{V}, I_D = 7\ \text{A}$		18.9	23	m $\Omega$
		$V_{GS} = 4.5\ \text{V}, I_D = 5.5\ \text{A}$		24.9	34	
		$V_{GS} = 10\ \text{V}, I_D = 7\ \text{A}, T_J = 125\text{ }^\circ\text{C}$		31.9	39	
$g_{FS}$	Forward Transconductance	$V_{DS} = 5\ \text{V}, I_D = 7\ \text{A}$		26		S

### Dynamic Characteristics

$C_{iss}$	Input Capacitance	$V_{DS} = 50\ \text{V}, V_{GS} = 0\ \text{V}, f = 1\ \text{MHz}$		999	1330	pF
$C_{oss}$	Output Capacitance			178	240	pF
$C_{rss}$	Reverse Transfer Capacitance			7.6	15	pF
$R_g$	Gate Resistance			0.5		$\Omega$

### Switching Characteristics

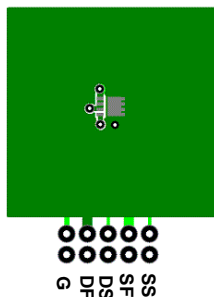
$t_{d(on)}$	Turn-On Delay Time	$V_{DD} = 50\ \text{V}, I_D = 7\ \text{A}, V_{GS} = 10\ \text{V}, R_{GEN} = 6\ \Omega$		7.7	16	ns	
$t_r$	Rise Time			2.2	10	ns	
$t_{d(off)}$	Turn-Off Delay Time			19	34	ns	
$t_f$	Fall Time			2.4	10	ns	
$Q_{g(TOT)}$	Total Gate Charge		$V_{GS} = 0\ \text{V to } 10\ \text{V}$		15	22	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0\ \text{V to } 4.5\ \text{V}$	$V_{DD} = 50\ \text{V}, I_D = 7\ \text{A}$		7.3	11	nC
$Q_{gs}$	Total Gate Charge				2.7		nC
$Q_{gd}$	Gate to Drain "Miller" Charge				2.3		nC

### Drain-Source Diode Characteristics

$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{GS} = 0\ \text{V}, I_S = 7\ \text{A}$ (Note 2)		0.81	1.3	V
		$V_{GS} = 0\ \text{V}, I_S = 2\ \text{A}$ (Note 2)		0.74	1.2	
$t_{rr}$	Reverse Recovery Time	$I_F = 7\ \text{A}, di/dt = 100\ \text{A}/\mu\text{s}$		45	72	ns
$Q_{rr}$	Reverse Recovery Charge			45	72	nC

#### NOTES:

1.  $R_{\theta JA}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta CA}$  is determined by the user's board design.



a) 53  $^\circ\text{C}/\text{W}$  when mounted on a 1 in<sup>2</sup> pad of 2 oz copper



b) 125  $^\circ\text{C}/\text{W}$  when mounted on a minimum pad of 2 oz copper

2. Pulse Test: Pulse Width < 300  $\mu\text{s}$ , Duty cycle < 2.0%.

3. Starting  $T_J = 25\text{ }^\circ\text{C}$ ; N-ch: L = 1 mH,  $I_{AS} = 11.3\ \text{A}$ ,  $V_{DD} = 90\ \text{V}$ ,  $V_{GS} = 10\ \text{V}$ .

**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted

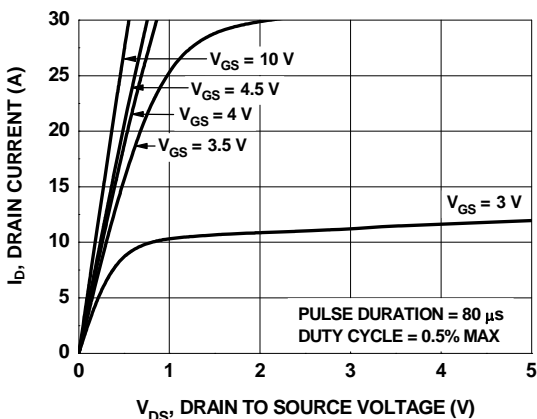


Figure 1. On Region Characteristics

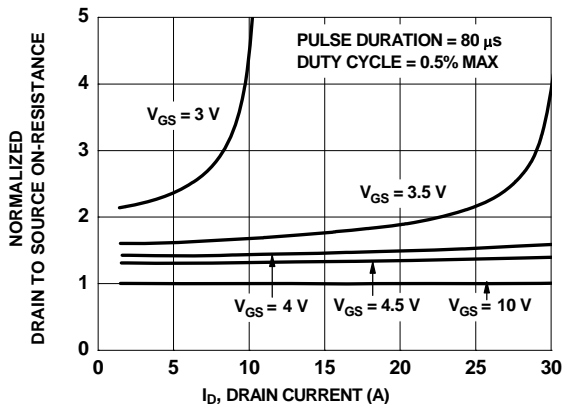


Figure 2. Normalized On-Resistance vs. Drain Current and Gate Voltage

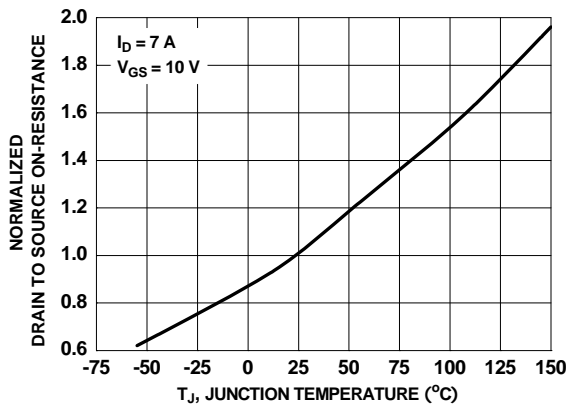


Figure 3. Normalized On Resistance vs. Junction Temperature

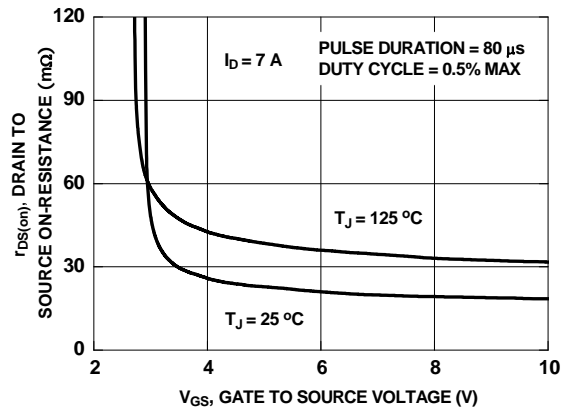


Figure 4. On-Resistance vs. Gate to Source Voltage

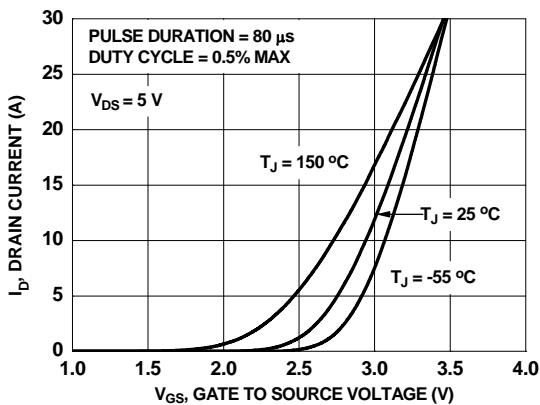


Figure 5. Transfer Characteristics

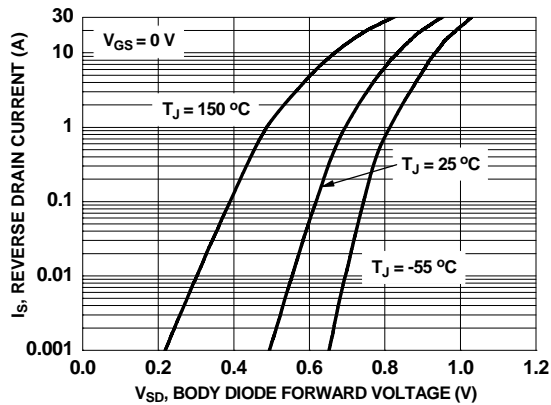
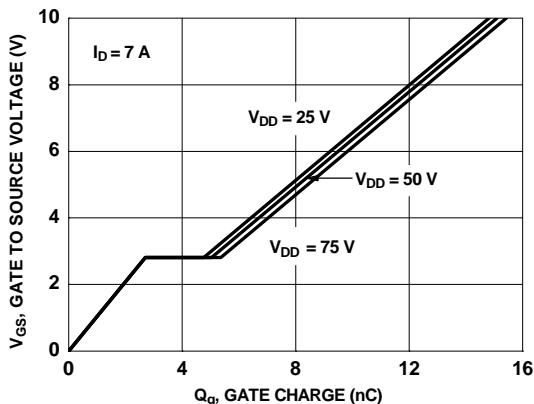
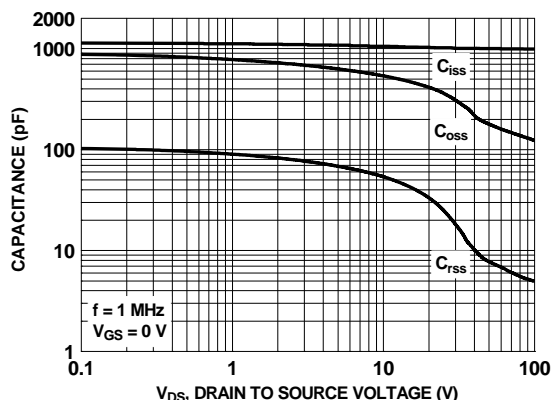


Figure 6. Source to Drain Diode Forward Voltage vs. Source Current

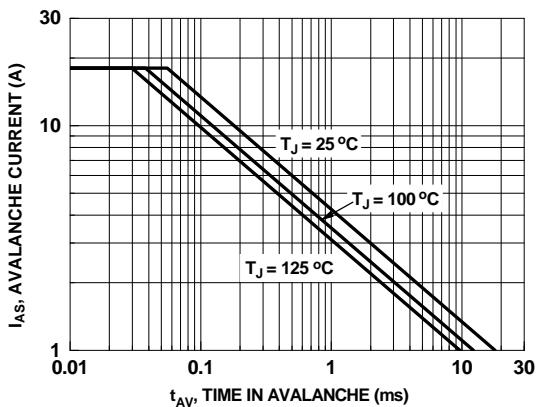
**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted



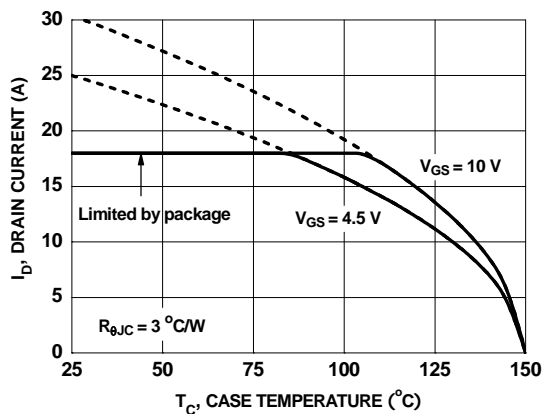
**Figure 7. Gate Charge Characteristics**



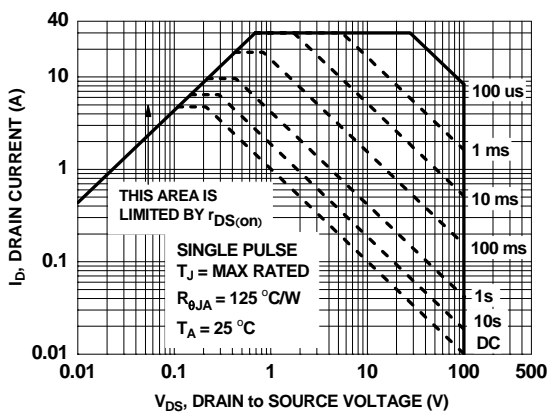
**Figure 8. Capacitance vs. Drain to Source Voltage**



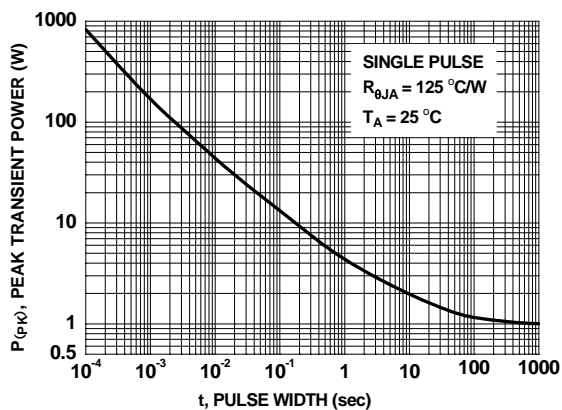
**Figure 9. Unclamped Inductive Switching Capability**



**Figure 10. Maximum Continuous Drain Current vs. Case Temperature**

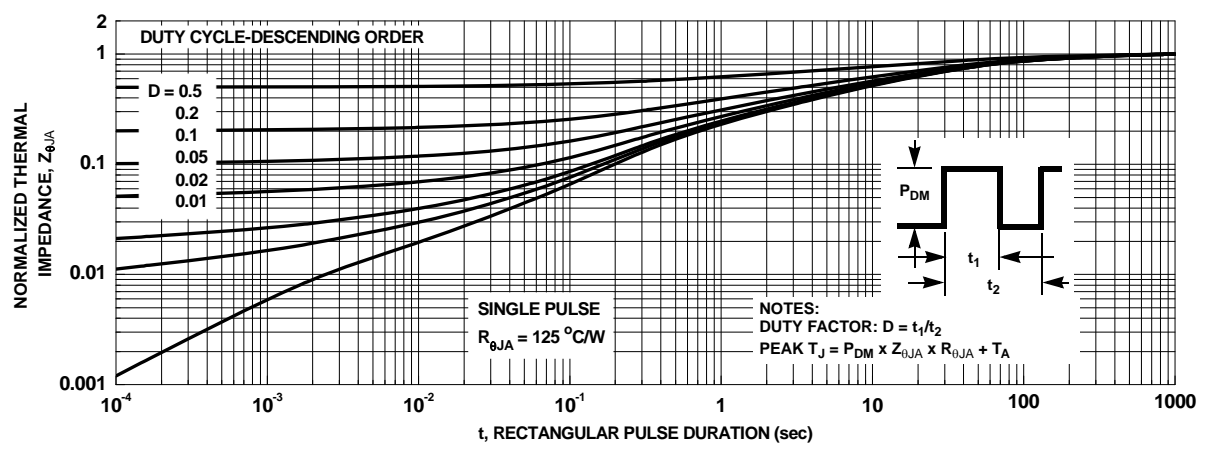


**Figure 11. Forward Bias Safe Operating Area**



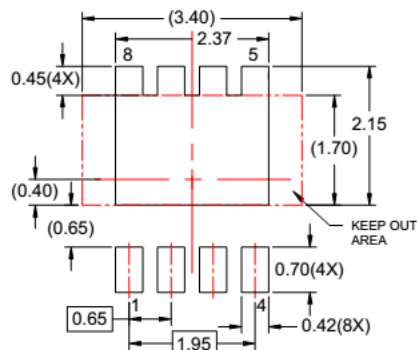
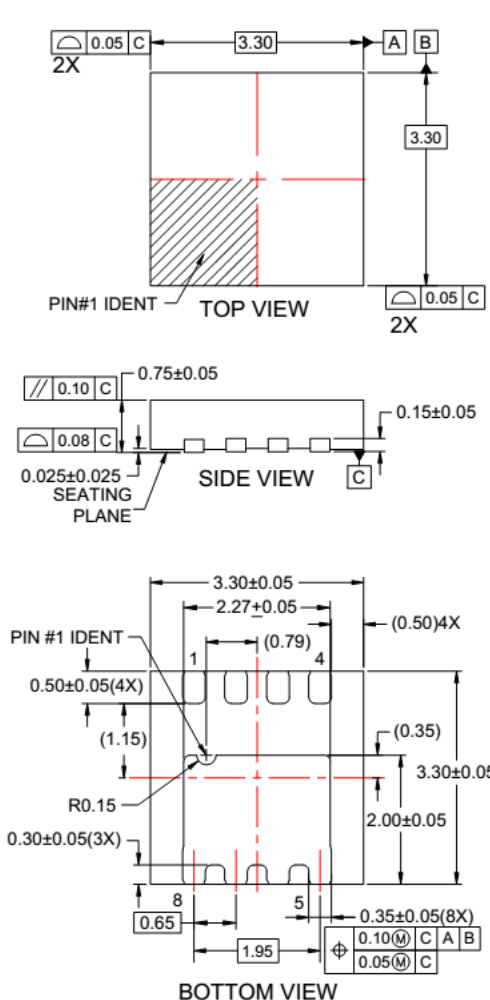
**Figure 12. Single Pulse Maximum Power Dissipation**

**Typical Characteristics**  $T_J = 25\text{ }^\circ\text{C}$  unless otherwise noted



**Figure 13. Junction-to-Ambient Transient Thermal Response Curve**

## Dimensional Outline and Pad Layout



RECOMMENDED LAND PATTERN

- NOTES:
- A. DOES NOT CONFORM TO JEDEC REGISTRATION MO-229
  - B. DIMENSIONS ARE IN MILLIMETERS.
  - C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 2009.
  - D. LAND PATTERN RECOMMENDATION IS EXISTING INDUSTRY LAND PATTERN.
  - E. DRAWING FILENAME: MKT-MLP08Srev3.





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